



#### P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> Max	<b>Ι</b> <sub>D</sub> T <sub>C</sub> = +25°C
-40V	9.9mΩ @ V <sub>GS</sub> = -10V	-50A
-40 v	14mΩ @ $V_{GS}$ = -4.5V	-45A

### Description

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- DC-DC Converters
- Power Management Functions
- Backlighting

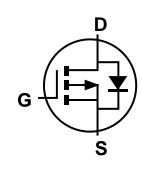
### TO252 D D D D D D D S Top View Pin-Out

## **Features and Benefits**

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



Equivalent Circuit

## Ordering Information (Note 5)

Top View

Part Number	Case	Packaging
DMP4010SK3Q-13	TO252	2,500/Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

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2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

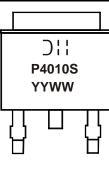
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

Notes:



>:! = Manufacturer's Marking P4010S = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 15 = 2015) WW = Week (01 to 53)



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-40	V		
Gate-Source Voltage			V <sub>GSS</sub>	±25	V
	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	ID	-50 -40	A
Continuous Drain Current (Note 7), $V_{GS} = -10V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-15 -12	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	-100	А
Maximum Body Diode Forward Current (Note 7)			Is	-5.5	A
Avalanche Current, L = 1mH (Note 8)			IAS	-22	A
Avalanche Energy, L = 1mH (Note 8)			E <sub>AS</sub>	260	mJ

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)		PD	1.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	73	°C/W
Total Power Dissipation (Note 7)		PD	3.3	W
Thermal Resistance, Junction to Ambient (Note 7) Steady State		R <sub>θJA</sub>	38	°C/W
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	1.0		
Operating and Storage Temperature Range		T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)						-	
Drain-Source Breakdown Voltage	<b>BV</b> <sub>DSS</sub>	-40	_	—	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Р	_	7.5	9.9	mΩ	$V_{GS} = -10V, I_D = -9.8A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	10.5	14	11152	$V_{GS} = -4.5V, I_D = -9.8A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		4234	—		$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	C <sub>oss</sub>	—	1036	-	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	526	_			
Gate Resistance	Rg	—	7.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	42.7	—			
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	91	_	nC	V <sub>DS</sub> = -20V, I <sub>D</sub> = -9.8A	
Gate-Source Charge	Q <sub>gs</sub>	_	14.2	—	nc		
Gate-Drain Charge	Q <sub>gd</sub>		13.5	_			
Turn-On Delay Time	t <sub>D(ON)</sub>		13.2	_		$V_{GS}$ = -10V, $V_{DD}$ = -20V, R <sub>G</sub> = 6Ω, I <sub>D</sub> = -1A	
Turn-On Rise Time	t <sub>R</sub>	_	10	_	1		
Turn-Off Delay Time	t <sub>D(OFF)</sub>		303	—	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	138	_	1		
Reverse Recovery Time	t <sub>RR</sub>	_	26	_	ns	I <sub>F</sub> = -9.8A, di/dt = -100A/µs	
Reverse Recovery Charge	Q <sub>RR</sub>	_	20	_	nC	I <sub>F</sub> = -9.8A, di/dt = -100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

8. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

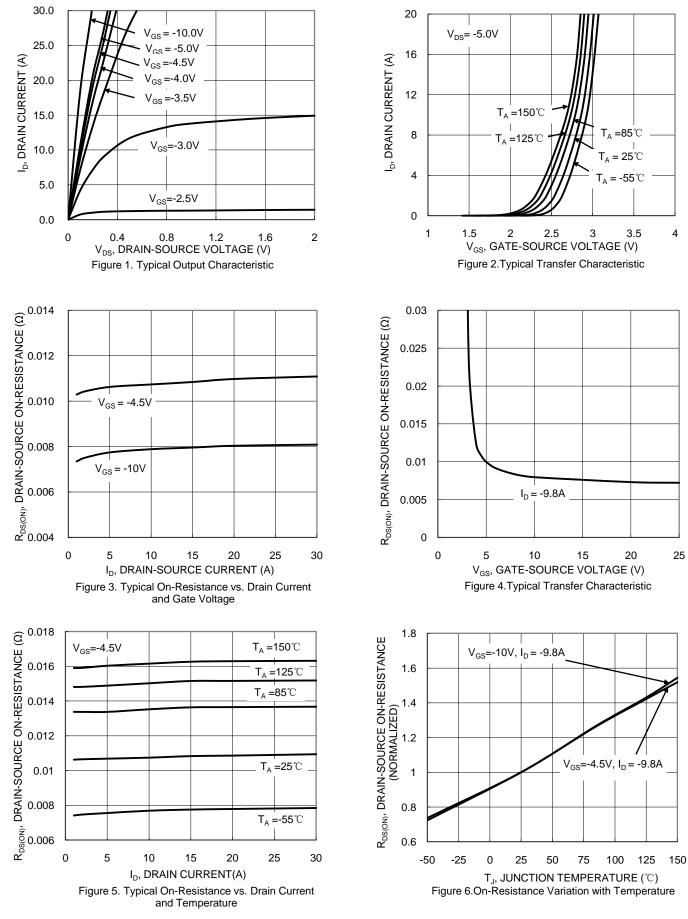
9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.



NEW PRODUCT

## DMP4010SK3Q

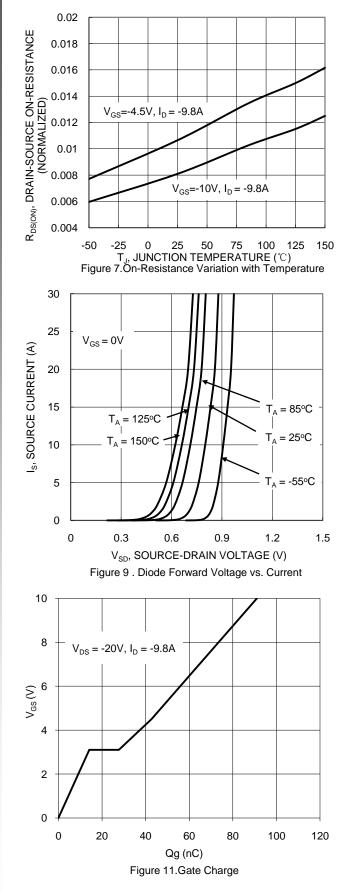


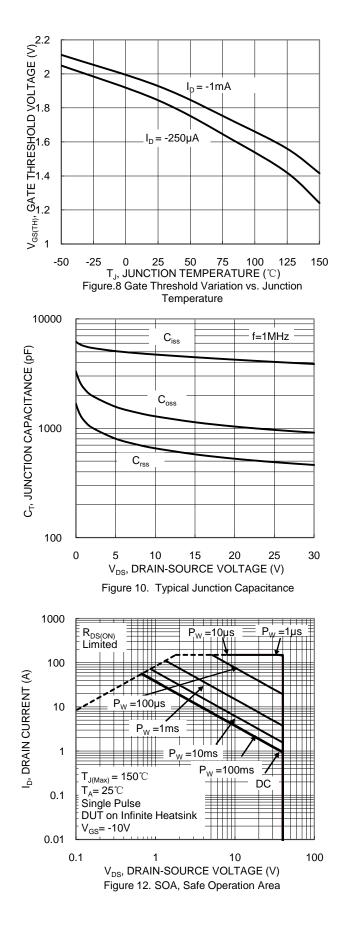
DMP4010SK3Q Document number: DS38124 Rev. 1 - 2



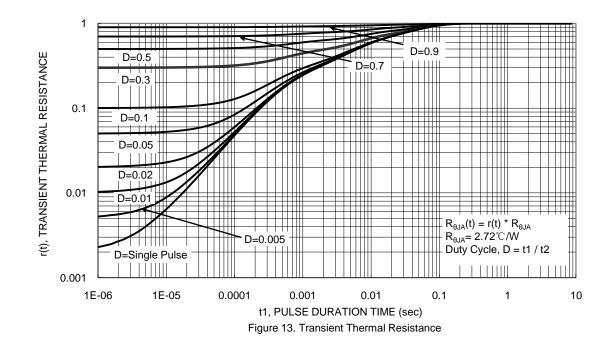
## DMP4010SK3Q

NEW PRODUCT





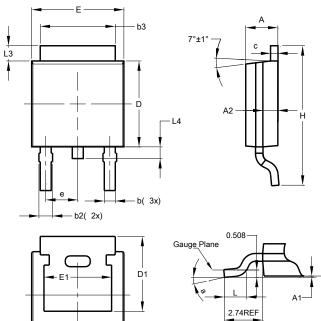






## **Package Outline Dimensions**

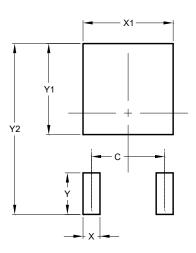
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



TO252 (DPAK)

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Seating Plane

Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			

TO252 (DPAK)

NEW PRODUCT



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